## NSN 5962-01-499-6901

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Between 0.500 inches and 0.610 inches

Body Length: 1.490 inches Body Width:



View Online at https://aerobasegroup.com/nsn/5962-01-499-6901

Body Height:	
0.217 inches	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
Features Provided:	
Hermetically sealed and burn in and monolithic and positive outputs	
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
N-type metal oxide-semiconductor logic	
Input Circuit Pattern:	
26 input	
Criticality Code Justification:	
Feat	
Case Outline Source And Designator:	
D-10 mil-m-38510	
Current Rating Per Characteristic:	
120.00 milliamperes reverse current, dc absolute	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Characteristic:	
-1.0 volts power source and 7.0 volts power source	
Capitance Rating Per Characteristic:	
6.00 input picofarads and 10.00 output picofarads	
Time Rating Per Chacteristic:	
250.00 nanoseconds access	
Memory Device Type:	
Eeprom	
Special Features:	
Nuclear hardness critical item	
Nuclear Hardness Critical Feature:	
Hardened	
Test Data Document:	
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.	).).

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ī	ermina	ı	Type	Δnd	Qua	antity.
ı	CHILLING	41	INDE	Allu	wu	aiititv.

28 printed circuit

Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

No

Fiig:

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